

TS4604

Stereo headset driver and analog audio line driver with integrated reference to ground

Features

- Operating from V_{CC} = 3 V up to 4.8 V single supply operation
- Line driver stereo differential inputs
- External gain setting resistors
- Space-saving package: TSSOP28 pitch 0.65 mm
- Dedicated shutdown control per function
- 100 mW headset drive into a 16 Ω load
- 90 dB high PSRR on headset drive
- Two internal negative supplies to ensure ground-referenced, headset and line driver capless outputs
- Internal undervoltage mute
- Line driver 2 Vrms typ. Output voltage across entire supply voltage range
- Pop-&-click reduction circuitry, thermal shutdown and output short-circuit protection

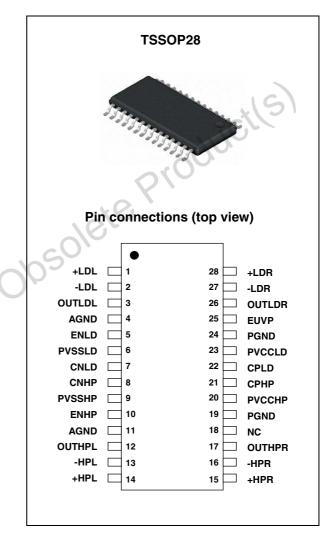
Applications

- PDP/LCD TV
- Set-top boxes

Description

The TS4604 is a stereo ground-referenced output analog line driver and stereo headset driver whose design allows the output DC-blocking capacitors to be removed, thus reducing component count. The TS4604 drives 2 Vrms into a 5 k Ω load or more. The device has differential inputs and uses external gain setting resistors.

The TS4604 delivers up to 100 mW per channel into a 16 Ω load. All outputs of the TS4604 include ±8 kV human body model ESD protection cells.



Contents

1	Abso	lute maximum ratings and operating conditions	. 3
2	Туріс	al application	. 4
3	Elect	rical characteristics	. 6
4		acteristics of the line driver	
5	Chara	acteristics of the headset driver	11
6	Appli	cation information	. 17
	6.1	General description	. 17
	6.2	Use of ceramic capacitors	18
	6.3	Flying and tank capacitor for the internal negative supply	18
	6.4	Power supply decoupling capacitor (Cs)	18
	6.5	Input coupling capacitor (Cin)	19
	6.6	Range of the gain setting resistors	19
	6.7	Performance of CMRR	21
	6.8	Internal and external undervoltage detection	21
		6.8.1 Internal UVLO	
		6.8.2 External UVLO	
	6.9	2nd order Butterworth low-pass filter	
	6.10	ESD protection and compliance	
105	6.11	Pop-&-click circuitry	
)•	6.12	Start-up phase	
	6.13	Layout recommendations	26
7	Pack	age information	27
	7.1	TSSOP28 package	28
8	Orde	ring information	29
9	Revis	sion history	30



1 Absolute maximum ratings and operating conditions

<u> </u>			
Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	5.5	V
V _{in}	Input voltage enable & standby pin ⁽²⁾	GND to V _{CC}	V
V _{in}	Input signal voltage	-2.5 to +2.5	V
T _{oper}	Operating free-air temperature range	-40 to + 85	°C
T _{stg}	Storage temperature	-65 to +150	°C
Тj	Maximum junction temperature	150	O°C
R _{thja}	Thermal resistance junction to ambient ⁽³⁾	200	°C/W
Pd	Power dissipation	Internally limited ⁽⁴⁾	
	Human body model for all pins except outputs Human body model for all output pins	P ² 8	kV
ESD	Machine model	200	V
	Charge device model	1500	V
Latch-up	Latch-up immunity	200	mA
	Lead temperature (soldering, 10sec)	260	°C

Table 1.	Absolute maximum	ratings	(AMR)
			(<i>/</i> ,

1. All voltage values are measured with respect to the ground pin.

2. The magnitude of the input signal must never exceed V_{CC} + 0.3 V/GND - 0.3 V.

3. The device is protected from overheating by a thermal shutdown mechanism active at 150° C.

4. Exceeding the power derating curves during a long period provokes abnormal operating conditions.

Table 2.Operating conditions

	Symbol	Parameter	Value	Unit
	V _{CC}	Supply voltage	3 to 4.8	V
26	Vicm	Common-mode input voltage range	From -1.4 to 1.4	V
SO	R _{LD}	Line drive load resistor	≥ 5	kΩ
005	R _{HD}	Headset drive load resistor	≥ 16	Ω
	R _{thja}	Thermal resistance junction-to-ambient ⁽¹⁾	80	°C/W

1. With heatsink surface = 125 mm^2 .

2 Typical application

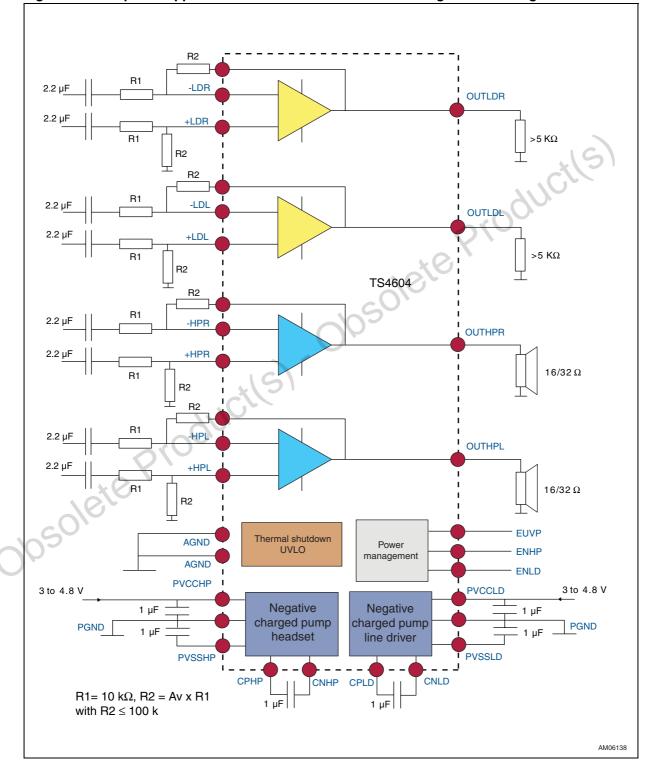


Figure 1. Simplified application schematics in differential configuration setting



Pin number	I/O ⁽¹⁾	Pin name	Pin description		
1	I	+LDL	Left line driver positive input channel		
2	I	-LDL	Left line driver negative input channel		
3	0	OUTLDL	Left line driver output channel		
4	Р	AGND	Analog line driver power ground		
5	I	ENLD	Line driver enable input pin (active high)		
6	0	PVSSLD	Output from line drive charge pump		
7	I/O	CNLD	Line driver charge pump flying capacitor negative terminal		
8	I/O	CNHP	Headset charge pump flying capacitor negative terminal		
9	I/O	PVSSHP	Output from headset drive charge pump		
10	I	ENHP	Headset driver enable input pin (active high)		
11	Р	AGND	Headphone analog input power ground		
12	0	OUTHPL	Left headset driver output channel		
13	I	-HPL	Left headset driver negative input channel		
14	I	+HPL	Left headset driver positive input channel		
15	I	+HPR	Right headset driver positive input channel		
16	I	-HPR	Right headset driver negative input channel		
17	0	OUTHPR	Right headset driver output channel		
18		NC	Not connected		
19	Р	PGND	Headset driver power ground		
20	Р	PVCCHP	Headset driver power supply voltage ⁽²⁾		
21	I/O	СРНР	Headset charge pump flying capacitor positive terminal		
22	I/O	CPLD	Line driver charge pump flying capacitor positive terminal		
23	Р	PVCCLD	Line driver power supply voltage ⁽²⁾		
24	Р	PGND	Line driver power ground		
25	I	EUVP	External undervoltage protection input pin		
26	0	OUTLDR	Right line driver output channel		
27	I	-LDR	Right line driver negative input channel		
28	I	+LDR	Right line driver positive input channel		

Table 3. Pin descriptions

1. I = input, O = output, P = power

2. PVccHP and PVccLD are internally connected, so PVccHP must be equal to PVccLD.



3 Electrical characteristics

Table 4.Common part: $V_{CC} = +3.3 V$, GND = 0 V, CPhp = CPld = 1 μ F, $T_{amb} = 25^{\circ}$ C
(unless otherwise specified)

VIL VENHP and VENLD Input voltage low VIH VENHP and VENLD Input voltage high IIH High level input current (ENHP and ENLD) IIL Low level input current (ENHP and ENLD) Fosc Internal negative voltage switching frequency, all temperaturange Vup External undervoltage detection threshold Ihyst External undervoltage detection hysteresis current	38 57 -1 -1 ure 400 1.15	40 60 550	43 66 1 1	% Vcc % Vcc μΑ μΑ
I _{IH} High level input current (ENHP and ENLD) I _{IL} Low level input current (ENHP and ENLD) F _{osc} Internal negative voltage switching frequency, all temperaturange Vup External undervoltage detection threshold Ihyst External undervoltage detection hysteresis current	-1 -1 Ire 400		1	μA
IL Low level input current (ENHP and ENLD) Fosc Internal negative voltage switching frequency, all temperaturange Vup External undervoltage detection threshold Ihyst External undervoltage detection hysteresis current	-1 Ire 400	550	1	-
Fosc Internal negative voltage switching frequency, all temperaturange Vup External undervoltage detection threshold Ihyst External undervoltage detection hysteresis current	^{1re} 400	550		μΑ
Fosc range Vup External undervoltage detection threshold Ihyst External undervoltage detection hysteresis current	400	550		
Ihyst External undervoltage detection hysteresis current	1.15		800	k Hz
		1.25	1.35	v
V/byst Dyss UD/LD Internal undervioltage detection bysterratio		5		μA
Vhyst Pvcc_HP/LD Internal undervoltage detection hysteresis	0	200		mV
Vuvl – power up – power down	SIG	2.8 2.6		v
Av Overall external gain (R2 ≤100 kΩ R1 = R2/Av)	0 1		20 10	dB V/V
solete Product(S)				



Symbol	Parameters and test conditions	Min.	Тур.	Max.	Unit
I _{cc}	Supply current (no input signal, no load)		5	6.5	mA
I _{ENHP}	Headset overall standby current (no input signal): $V_{ENHP} = GND$ $V_{ENHP} = 38\% V_{CC}$		1	5 100	μA
V _{io}	Input offset voltage	-7	0	7	mV
Po	Headphone output power: THD + N = 1% max, f = 1 kHz, BW = 22 kHz, R _L = 16 Ω	45	65		mW
Po	Headphone output power: THD + N = 1% max, f = 1 kHz, BW = 22 kHz, R _L = 32 Ω	30	45	.ct	SmW
THD + N	Total harmonic distortion + noise: $R_L = 16 \Omega$, $P_o = 60$ mW, f = 20 Hz to 20 kHz, BW = 22 kHz		0.05	00	%
PSRR	Headphone power supply rejection ratio with AC inputs grounded: $f = 217 \text{ Hz}$, $V_{ripple} = 200 \text{ mV}_{pp}$	2	90		dB
t _{WU}	Total wake-up time	0	30		ms
t _{STBY}	Standby time		20		μs
Xtalk	Crosstalk headphone to line: Pout = 50 mW, $R_L = 16 \Omega$, f = 20 Hz to 20 kHz		-100		dB
SNR	Signal-to-noise ratio (A-weighting): $R_L = 16 \Omega$, $P_o = 60$ mW		102		dB
CMRR	Common-mode rejection ratio: f = 20 Hz to 20 kHz, Vic = 200 mVpp		-70		dB
V _N	Output voltage noise: f = 20 Hz to 20 kHz, A-weighted		7.6		μV _{RMS}
CL ⁽¹⁾	Capacitive load: $R_L = 16 \Omega \text{ to } 100 \Omega$ $R_L > 100 \Omega$			400 100	pF

Headset driver part: V_{CC} = +3.3 V, GND = 0 V, Table 5.

1. Higher capacitive loads are possible by adding a serial resistor of 47 Ω in the line driver output. Josol

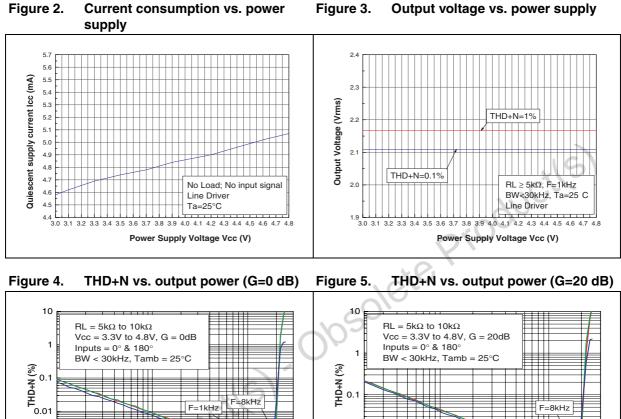


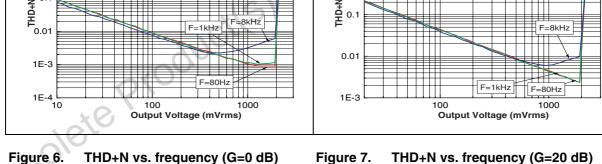
Symbol	Parameters and test conditions	Min.	Тур.	Max.	Unit
I _{cc}	Supply current (no input signal, no load)		5	6.5	mA
I _{ENLD}	Line drive standby current (no input signal) $V_{ENLD} = GND$ $V_{ENLD} = 38\% V_{CC}$			5 100	μΑ
V _{io}	Input offset voltage	-7	0	+7	mV
V _{SWING}	Output voltage swing: $R_L = 10 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, THD+N = 0.1%		2.1		Vrms
PSRR	Line driver power supply rejection ratio with AC inputs grounded: f = 217 Hz, V_{ripple} = 200 mV _{pp}		90		dB
t _{WU}	Wake-up time from shutdown		30	5	ms
t _{STBY}	Standby time		20	•	μs
SNR	Signal-to-noise ratio (A-weighting): Vin = 1.7 Vrms	X	102		dB
V _N	Output voltage noise: f = 20 Hz to 20 kHz, A-weighted	e .	8		μV _{RMS}
GBw	Gain bandwidth product		1		MHz
Sr	Slew rate		0.5		V / µs
THD+N	BW = 22 kHz, R _L = 10 k Ω , V _O = 1.5 Vrms, Av = 1, f = 20 Hz to 20 kHz		0.001		%
CMRR	f = 20 Hz to 20 kHz, Vic = 200 mVpp		-70		dB
Xtalk	Crosstalk channel: f = 20 Hz to 20 kHz, Vo = 1.5 Vrms, $R_L = 5 k\Omega$		-120		dB
CL ⁽¹⁾	Capacitive load: $R_L > 5 k\Omega$			400	pF

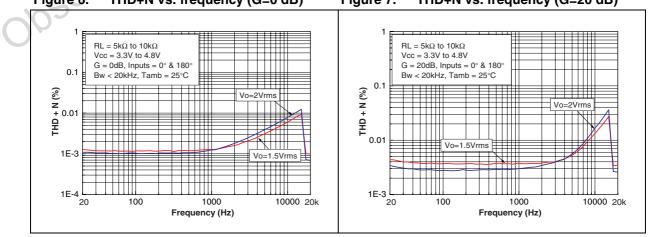
1. Higher capacitive loads are possible by adding a serial resistor of 47 Ω in the line driver output.



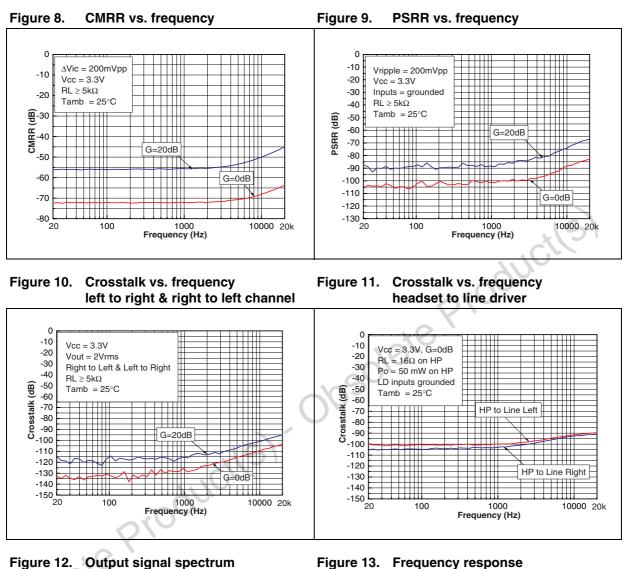
4 Characteristics of the line driver

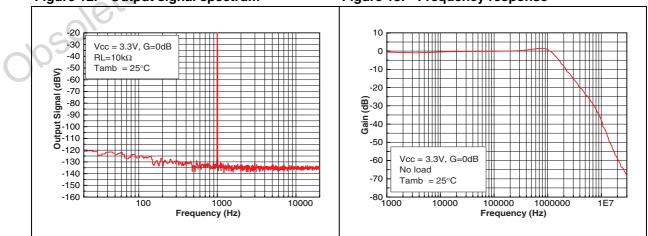






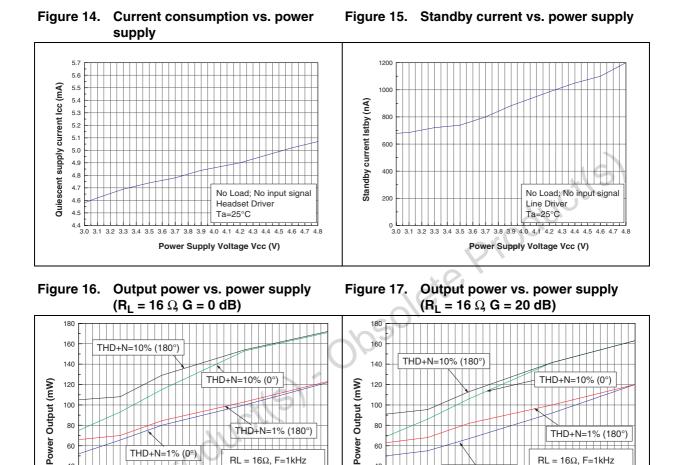






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Characteristics of the headset driver 5



100

80

60

40

20

THD+N=1% (180°)

 $RL = 16\Omega$, F=1kHz

Headset Driver

BW<30kHz, Ta=25 C

G=0dB

3.0 3.1 3.2 3.3 3.4 3.5 3.6 3.7 3.8 3.9 4.0 4.1 4.2 4.3 4.4 4.5 4.6 4.7 4.8

Power Supply Voltage Vcc (V)



100

80

60

40

20

THD+N=1% (0°)

THD+N=1% (180°)

BW<30kHz, Ta=25 C

 $RL = 16\Omega$, F=1kHz

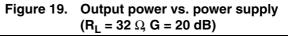
Headset Driver

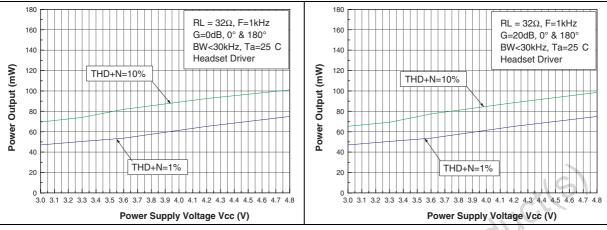
G=20dB

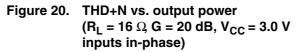
THD+N=1% (0°)

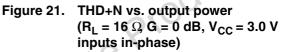
0 4.1 4.2 4.3 4.4 4.5 4.6 4.7 4.8 3.0 3.1 3.2 3.3 3.4 3.5 3.6 3.7 3.8 3.9 4.0 4.1 4.2 4.3 4.4 4.5 4.6 4.7 4.8

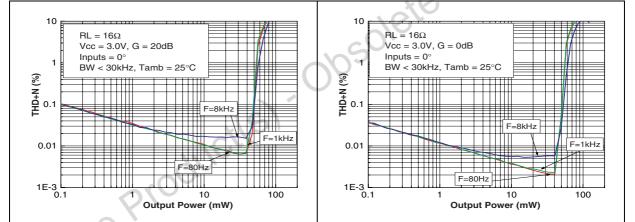
Power Supply Voltage Vcc (V)

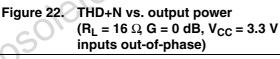


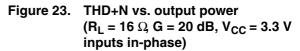


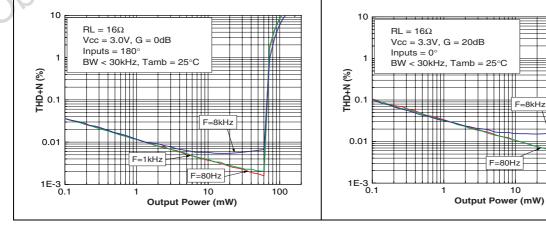












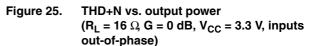


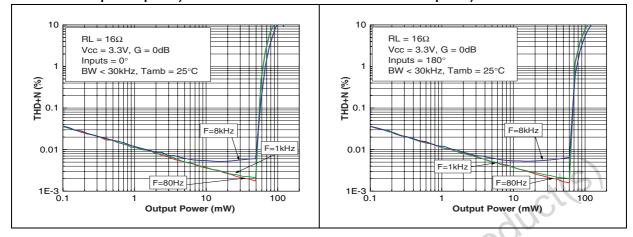
F=1kHz

100

1111

Figure 24. THD+N vs. output power ($R_L = 16 \Omega$, G = 0 dB, $V_{CC} = 3.3 V$ inputs in-phase)





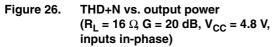


Figure 27. THD+N vs. output power ($R_L = 16 \Omega$, G = 0 dB, V_{CC} = 4.8 V inputs in-phase)

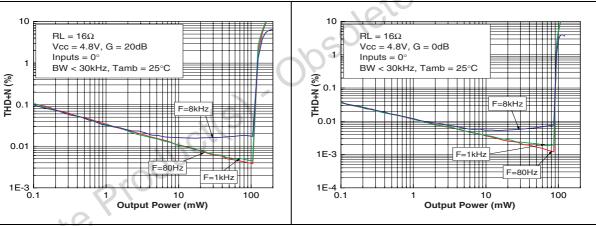
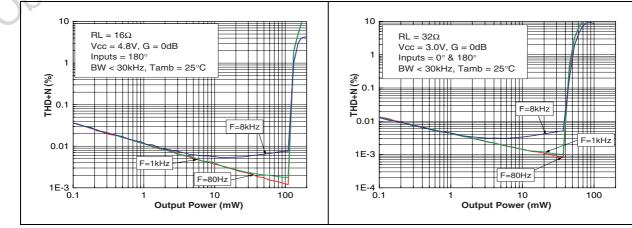
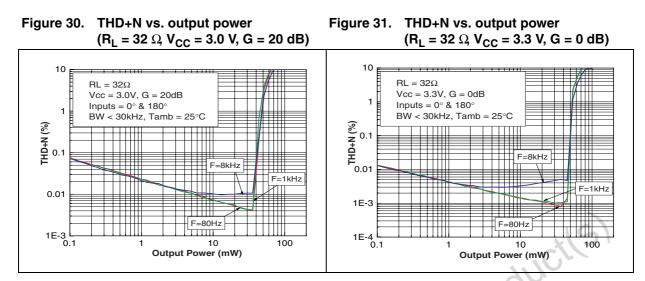


Figure 28. THD+N vs. output power ($R_L = 16 \Omega$, G = 0 dB, V_{CC} = 4.8 V inputs out-of-phase)

Figure 29. THD+N vs. output power ($R_L = 32 \ \Omega$, $V_{CC} = 3.0 \ V$, $G = 0 \ dB$)







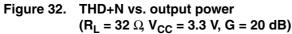
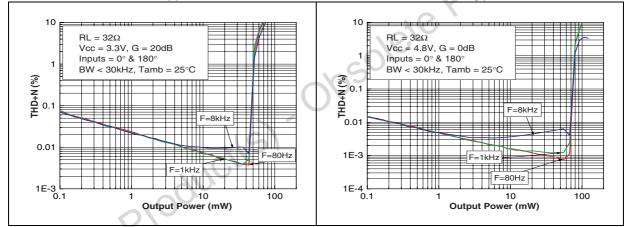
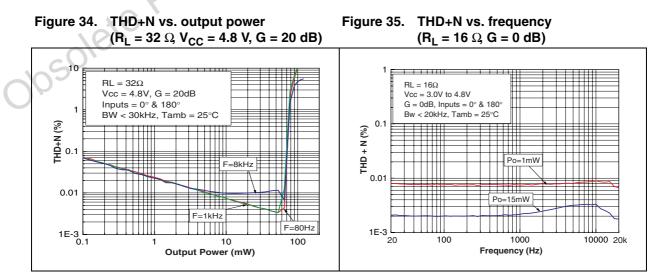


Figure 33. THD+N vs. output power ($R_L = 32 \Omega$, $V_{CC} = 4.8 V$, G = 0 dB)

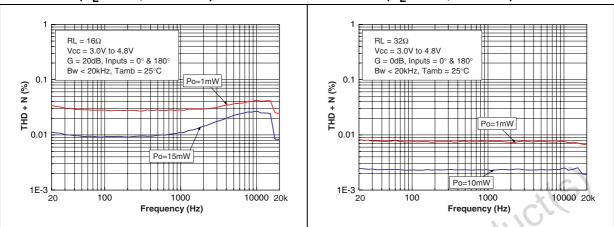


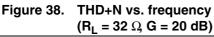


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Figure 36. THD+N vs. frequency Fig ($R_L = 16 \Omega, G = 20 \text{ dB}$)

Figure 37. THD+N vs. frequency ($R_1 = 32 \Omega_1 G = 0 dB$)





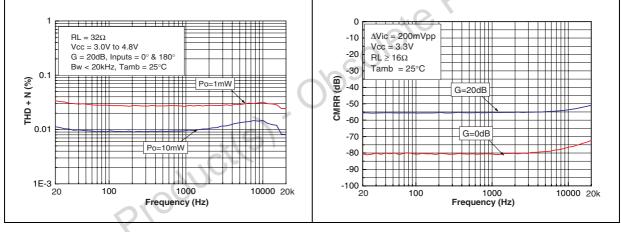
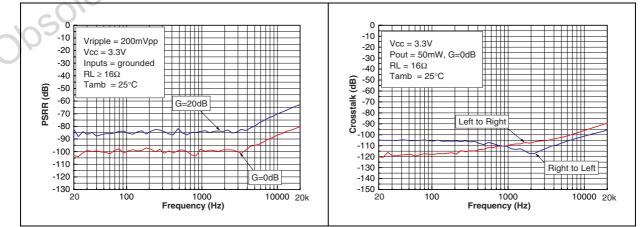


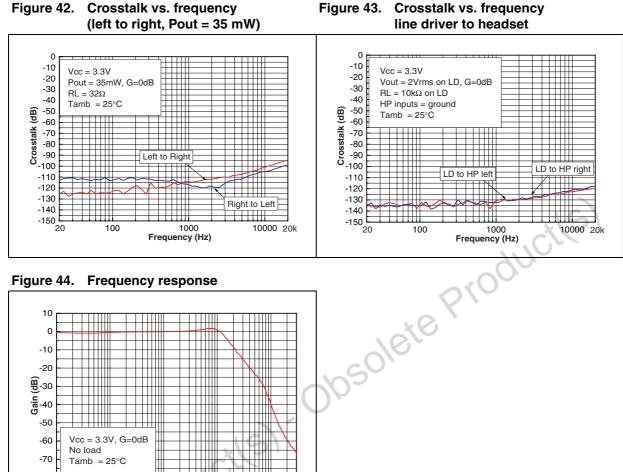


Figure 41. Crosstalk vs. frequency (left to right, Pout = 50 mW)

Figure 39. CMRR vs. frequency (headset)



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1E7

100000 1000000 Frequency (Hz)

Figure 43. Crosstalk vs. frequency

04-ai

-50

-60

-70

-80 L_____ 1000

Obsolete

Tamb = $25^{\circ}C$

10000

No load

Vcc = 3.3V, G=0dB



6 Application information

6.1 General description

The TS4604 is a stereo headset driver and a ground-referenced stereo audio line driver. To save energy, each audio path, line driver or headphone can be independently set to standby mode.

The headphone delivers up to 100 mW into a 16 Ω load, and the line driver drives up to 2 Vrms into 5k or more. The gain can be set up to 20 dB by changing the values of the external gain resistors.

The outputs of the headphone and line driver are protected against overloads. Overloads can occur when the outputs are short-circuited between them or to Gnd or to V_{CC} . There is also an internal thermal shutdown activated at 150°C (typical) and deactivated at 120°C (typical).

To remove the bulky output DC blocking capacitor and maximize the output swing of the amplifier, the TS4604 embeds a low noise internal negative supply. All amplifiers are supplied between a positive voltage +Vp and a negative voltage -Vn. With this architecture, the output voltage is centered on 0 V, allowing the swing of the output voltage between the positive rail, as depicted in *Figure 45*.

Both the line driver and headset driver use this architecture.

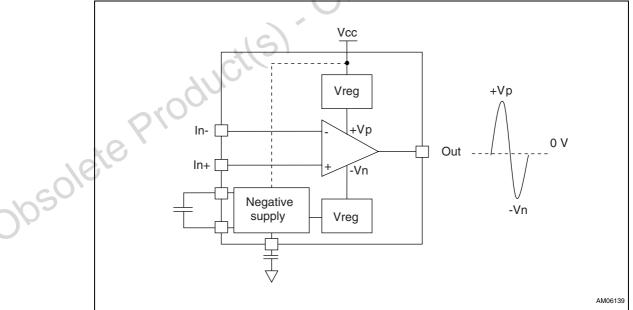


Figure 45. TS4604 voltage for one channel

Note:

The PVSSHP and PVSSLD voltages are generated internally by the internal negative supply. **To avoid damage to the TS4604, do not connect an external power supply on the PVSSHP and PVSSLD pins**.



6.2 Use of ceramic capacitors

We advise using ceramic capacitors for the decoupling, flying or tank capacitors because of their low ESR properties. The rated voltage of the ceramic capacitor, however, is an important parameter to take into consideration.

A 1 μ F/6.3 V capacitor used at 4.8 V DC typically loses about 40% of its value. In fact, with a 4.8 V power supply voltage, the decoupling value is about 0.6 μ F instead of 1 μ F. Because the decoupling capacitor influences the THD+N in the medium-to-high frequency region, this capacitor variation becomes decisive. In addition, less decoupling means higher overshoots, which can be problematic if they reach the power supply's AMR value (5.5 V).

This is why it is recommend to use a 1 μ F/10 V/X5R or a 2.2 μ F/6.3 V/X5R, or a new kind of ceramic capacitor with a low DC bias variation rated at 6.3 V.

If a 1 μ F/10 V ceramic capacitor is used, at 4.8 V the capacitance will be 0.82 μ F, C

If a 2.2 μ F/6.3 V ceramic capacitor is used, at 4.8 V the capacitance will be 1.1 μ F.

6.3 Flying and tank capacitor for the internal negative supply

The TS4604 embeds two independent internal negative supplies as shown in *Figure 1*. Each of them requires two capacitors to work properly (a flying and a tank capacitor). The internal negative supply capacitor must be correctly selected to generate an efficient negative voltage.

Two flying capacitors (CHP and CLD) of 1 μ F each with low ESR are recommended for internal negative power supply operation.

- CHP between pins 8 and 21.
- CLD between pins 7 and 22.

Two tank capacitors (CPvss_HP and CPvss_LD) of 1 µF each with low ESR are recommended for internal negative power supply energy storage.

- CPvss_HP between pin 9 and ground.
- CPvss_LD between pin 6 and ground.

An X5R dielectric for capacitor tolerance should be used. In order to take into consideration the $\Delta C/\Delta V$ variation of this type of dielectric (see *Section 6.2* above), we also recommend:

- a 10 V DC rating voltage for 4.8 V power supply operation.
- a 6.3 V DC rating operation for 3.3 V power supply operation.

These capacitors must be placed as close as possible to the TS4604 to minimize parasitic inductance and resistance that have a negative impact on the audio performance.

6.4 Power supply decoupling capacitor (Cs)

A 1 μ F decoupling capacitor (Cs) with low ESR is mandatory for the positive power supply X5R dielectric for capacitor tolerance behavior. In order to take into consideration the Δ C/ Δ V variation of this type of dielectric (see *Section 6.2* above), it is also recommended to use:

- a 10 V DC rating voltage for 4.8 V power supply operation.
- a 6.3 V DC rating operation for 3.3 V power supply operation.



These capacitors must be placed as close as possible to the TS4604 to minimize parasitic inductance and resistance that have a negative impact on the audio performance.

6.5 Input coupling capacitor (Cin)

An input coupling capacitor (Cin) might be used for TS4604 operation to block any DC component of the audio signal.

Cin starts to have an effect in the low frequency region. Cin forms with Rin a high-pass filter with a -3 dB cut-off frequency.

$$Fc(-3dB) = \frac{1}{2.\pi \cdot Rin \cdot Cin}(Hz)$$

Example

A differential input gain as shown in *Figure 46 on page 20* with the gain equalling 0 dB (Rin = 10 k Ω , Rfd = 10 k Ω) and an input capacitor of 2.2 µF gives:

$$Fc = \frac{1}{2.\pi \cdot 10000 \cdot 2.2e10^{-6}} = 7.2Hz$$

The high-pass filter has a -3 dB cut-off frequency at 7.2 Hz in this case.

6.6 Range of the gain setting resistors

The TS4604 can be use in different configurations, as shown in figures 46, 47 and 48.

The gain is given by the external resistors Rfd divided by Rin. The feedback resistor Rfd does not exceed 100 k Ω for closed-loop stability reasons.

Table 7 gives the recommended resistor values and the gain for different types of application.

	Rin	Rfd	Differential gain	Inverting gain	Non-inverting gain
\bigcirc	1 0 kΩ	10 kΩ	0 dB	0 dB	6 dB
	10 kΩ	20 kΩ	6 dB	6 dB	10 dB
	10 kΩ	50 k Ω	14 dB	14 dB	16 dB
	4.7 kΩ	47 kΩ	20 dB	20 dB	21 dB
	10 kΩ	100 kΩ	20 dB	20 dB	21 dB

Table 7. Recommended resistors values



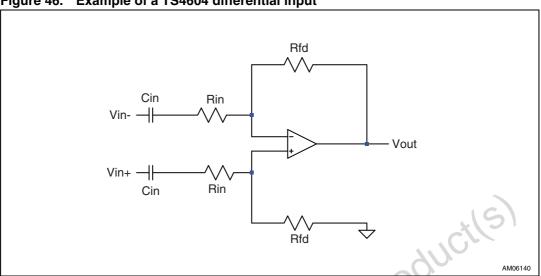
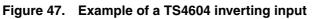
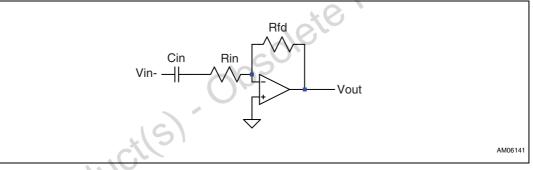
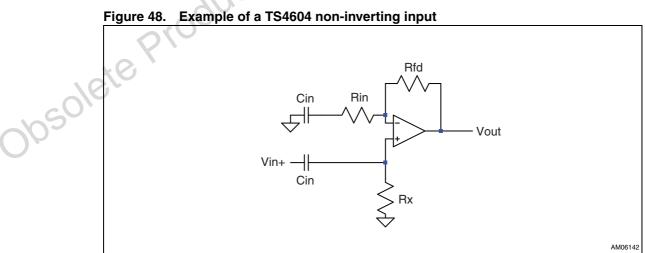


Figure 46. Example of a TS4604 differential input









6.7 Performance of CMRR

When the TS4604 is used in differential mode (*Figure 46*), because of the resistor matching the CMRR can have important variations.

To minimize these variations, we recommend using the same kind of resistor (same tolerance).

The following equation is valid for frequencies ranging from DC to about kHz. The equation is simplified by neglecting the ΔR^2 terms. ΔR is the tolerance value as a percentage.

$$CMRR \approx 20 \cdot log \left[\frac{100}{4\Delta R} \left(1 + \frac{Rfd}{Rin}\right)\right] (dB)$$

It is extremely important to correctly match the resistors to obtain a good CMRR.

All the tests have been performed with resistors with a tolerance value of 0.1%.

Example:

With $\Delta R = 1\%$ the minimum CMRR would be 34 dB.

With $\Delta R = 0.1\%$ the minimum CMRR would be 54 dB.

6.8 Internal and external undervoltage detection

The TS4604 embeds two UVLOs: one internal and one external.

6.8.1 Internal UVLO

The internal UVLO monitors the power supply via pins PVCC_HP (20) and PVCC_LD(23). The threshold is set to 2.8 V with a 200 mV hysteresis. If the power supply decreases to 2.6 V, the TS4604 switches to standby mode. To switch the device on again, the power supply voltage must increase to above 2.8 V.

Refer to *Table 4* for the tolerance of the UVLO voltage.

6.8.2 External UVLO

The Ex_UVP pin (25) is an external undervoltage detection input that can be used to start up or shutdown the TS4604 by applying the correct voltage value. A 1.25 V internal precision voltage is used as a reference to monitor the voltage applied to the Ex_UPVP pin.

To set a desired shutdown threshold and hysteresis for the application, a resistor divider can be calculated as follows.

$$Vuvp = 1.25V \cdot \frac{(R1 + R2)}{R1}$$

Vhyst
$$\approx 5\mu A \cdot R3 \cdot \left(\frac{R2}{R1} + 1\right)$$

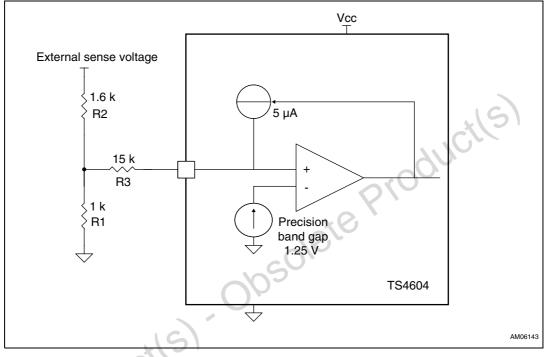
with the condition R3>>R1//R2.



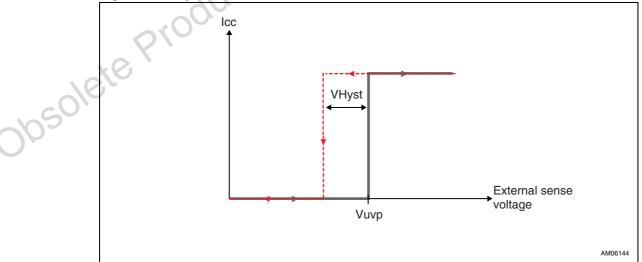
For example, to obtain Vuvp = 3.3 V with a hysteresis of 200 mV:

- R1 = 1 kΩ
- R2 = 1.6 kΩ
- R3 = 15 kΩ









When the external sense voltage (ESV) increases, the TS4604 stays in standby mode until the EUVP pin reaches 1.25 V (voltage across the divider R1, R2). At this point, the TS4604 starts, as does the internal 5 μ A current source connected to the EUVP pin. Thanks to this 5 μ A current, a voltage drop is created across the R3 resistor.



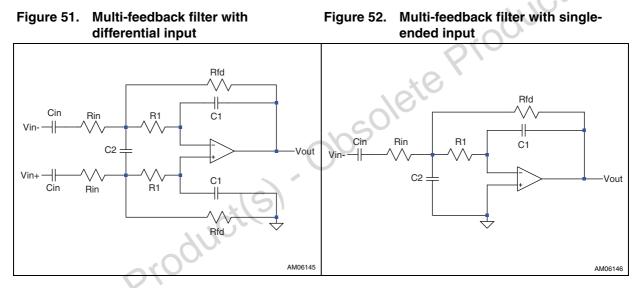
To switch the TS4604 back to standby, the voltage across the divider R1, R2 has to be lower than 1.25 V - VHyst \times R1/(R1 + R2). The ESV can be an external voltage or simply the power supply voltage PVcc_LD/HD.

6.9 2nd order Butterworth low-pass filter

The TS4604 can also be configured as a low-pass filter to be driven directly by a DAC output. It can be used, for example, as a 2nd order low-pass filter, with either a differential input or a single-ended input.

Figure 51 and *Figure 52* depict these two kinds of application and represent a multiple feedback 2nd order low-pass filter.

An AC-coupling capacitor should be added to block any DC component from the source, which helps to reduce the output DC offset to a minimum.



Example 2nd-order multi-feedback filter in differential mode

Figure 53 shows a filter in differential mode with a cut-off frequency at 30 kHz (configured as per the values in *Table 8*, which proposes various filter options using a differential input).



ns



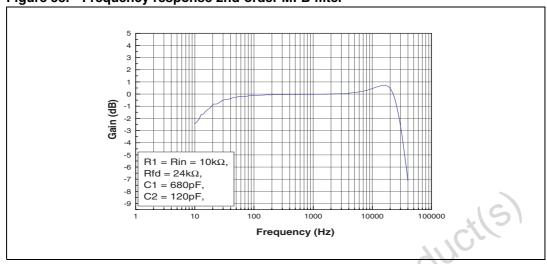


Figure 53. Frequency response 2nd-order MFB filter

Table 8.	Recommended values for 2nd order low-pass filter

Low-pass filter	Rin	R1	Rfd	C1	C2
25 kHz	10 k Ω	10 kΩ	15 kΩ	1 nF	200 pF
30 kHz	10 k Ω	10 kΩ	24 kΩ	680 pF	120 pF

6.10 ESD protection and compliance

To provide excellent ESD immunity, an audio line IPAD^(a) (STMicroelectronics reference EMIF04-EAR02M8) can be added at the output of the TS4604 (*Figure 54*).

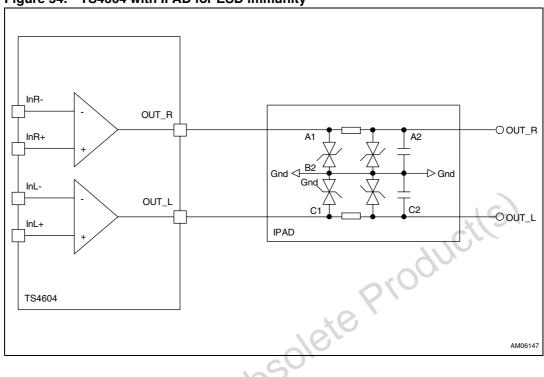
By adding the IPAD, the TS4604 complies with the standard IEC 61000-4-2 level 4 on the external pins.

- OUT_HPL and OUT_HPR for the headphone driver.
- OUT_LDL and OUT_LDR for the Line driver.



a. Copyright ST Microelectronics.

Figure 54. TS4604 with IPAD for ESD immunity



6.11 Pop-&-click circuitry

Thanks to the internal negative supply the headphone and line driver outputs are referred to ground without the need for bulky in-series capacitors. As a result, the pop created by these bulky capacitors is eliminated. In addition, the TS4604 includes a pop-&-click circuitry that suppresses any residual pop on the outputs, thus enabling the outputs to be virtually pop-&-click-free.

6.12 Start-up phase

To further improve the pop-&-click performance, two important points must be taken into account during the start-up phase.

Input capacitor

During the start up phase, as long as the AC input coupling capacitors are not fully charged, we suggested to remain the EN_LD and En_HP and/or Ext_UVP pin low.

The constant time for an RC filter is given by:

 $\tau = Rin \cdot Cin$

We can consider that the input capacitor Cin will be charged at 95% of its maximum value at:

 $T = 3\tau$



With a gain set at G = 0 dB, a Rin = 10 k Ω and Cin = 2.2 μ F, to charge Cin to 95% of its final value, 66 ms are necessary.

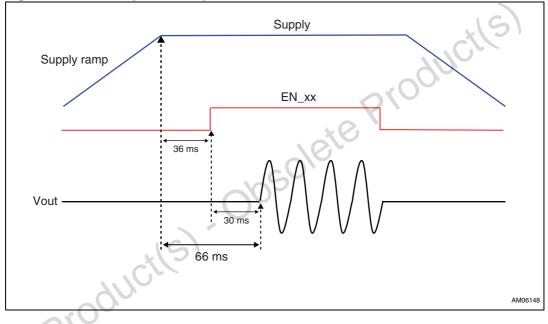
Wake-up time of the TS4604

The TS4604 needs 30 ms to become fully operational (see *Table 5* and *Table 6*).

The total startup sequence with the settings described being 66 ms, and since the TS4604 needs 30 ms to wake up, the Enable pin for the line driver and/or headphone can be set high 36 ms after the power supply has reached its normal value (*Figure 55*).

With a lower input capacitance, the startup phase is quicker.

Figure 55. Power-up/down sequence



6.13 Layout recommendations

Particular attention must be given to the correct layout of the PCB traces and wires between the amplifier, load and power supply.

The power and ground traces are critical since they must provide adequate energy and grounding for all circuits. Good practice is to use short and wide PCB traces to minimize voltage drops and parasitic inductance.

Proper grounding guidelines help improve audio performances, minimize crosstalk between channels, and prevent switching noise from coupling into the audio signal. It is also recommended to use a large-area and multi-via ground plane to minimize parasitic impedance.

Connect all the V_{CC} tracks (PVCCLD and PVCCHP) to one point one the board.

The copper traces that connect the output pins to the load and supply pins should be as wide as possible to minimize the trace resistances.

The gain setting resistors must be placed as close as possible to the input in order to minimize the parasitic capacitors on these inputs pins.

TS4604

7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



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7.1 TSSOP28 package

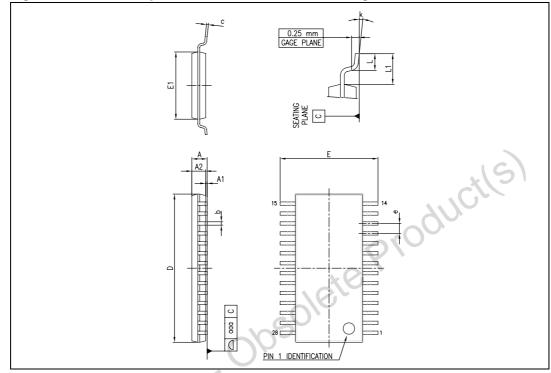


Figure 56. TSSOP28 pitch 0.65 mm mechanical drawing

Table 9. TSSOP28 pitch 0.65 mm mechanical data

		, C		Dime	nsions			
	Ref.	-90-	Millimeters			Inches		
	20	Min.	Тур.	Max.	Min.	Тур.	Max.	
	A			1.20			0.047	
10	A1	0.05		0.15	0.002		0.006	
c01	A2	0.80	1.00	1.05	0.031	0.039	0.041	
05	b	0.19		0.30	0.007		0.011	
U.	с	0.09		0.20	0.003		0.008	
	D	9.60	9.70	9.80	0.378	0.382	0.386	
	E	6.20	6.40	6.60	0.244	0.252	0.260	
	E1	4.30	4.40	4.50	0.170	0.173	0.177	
	е		0.65			0.026		
	L	0.45	0.60	0.75	0.018	0.024	0.030	
	L1		1.00			0.040		
	k	0		8				
	aaa			0.10			0.004	



8 Ordering information

Table 10. Order codes

Part number	Temperature range	Gain	Package	Marking
TS4604IPT	-40°C, +85°C	External	TSSOP28	4604



obsolete Product(s). Obsolete Product(s)

9 Revision history

Table 11. Document revision history

Date	Revision	Changes	
27-Oct-2010	1	Initial release.	

obsolete Product(s). Obsolete Product(s)



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